

HEXFRED® Ultrafast Diodes, 100 A (INT-A-PAK Power Modules)



| PRIMARY CHARACTERISTICS | | | | |
|--------------------------------------|----------------------------|--|--|--|
| V_{R} | 1200 V | | | |
| V _F (typical) | 2.5 V | | | |
| t _{rr} (typical) | 150 ns | | | |
| I _{F(DC)} at T _C | 110 A at 100 °C | | | |
| Package | INT-A-PAK | | | |
| Circuit configuration | Two diodes doubler circuit | | | |

FEATURES





- Standard JEDEC® package
- · Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL approved file E78996
- Case style INT-A-PAK
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

| ABSOLUTE MAXIMUM RATINGS | | | | | |
|--|-----------------------------------|---|-------------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Cathode to anode voltage | V_{R} | | 1200 | V | |
| Continuous forward current | | T _C = 25 °C | 205 | | |
| | I _F | T _C = 100 °C | 110 | Α | |
| Single pulse forward current | I _{FSM} | Limited by junction temperature | 800 | | |
| Maximum navvar dissination | P _D | T _C = 25 °C | 695 | W | |
| Maximum power dissipation | | T _C = 100 °C | 280 | | |
| RMS isolation voltage | V _{ISOL} | 50 Hz, circuit to base, all terminal shorted, t = 1 s | 3500 | V | |
| Operating junction and storage temperature range | T _J , T _{Stg} | | -40 to +150 | °C | |

| ELECTRICAL SPECIFICATIONS PER LEG (T _J = 25 °C unless otherwise specified) | | | | | | |
|--|-----------------|--|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Cathode to anode breakdown voltage | V_{BR} | Ι _R = 100 μΑ | 1200 | - | - | |
| Maximum forward voltage V _{FM} | V | I _F = 100 A | - | 2.5 | 3.2 | V |
| | VFM | I _F = 160 A | - | 2.9 | 3.9 | |
| Maximum reverse leakage current | I _{RM} | T _J = 150 °C, V _R = 1200 V | - | 18 | 30 | mA |



| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|---|--------------------------|------------------------|--|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 150 | 200 | ns |
| Reverse recovery current | I _{RRM} | T _J = 25 °C | $I_F = 160 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ | - | 20 | 22 | Α |
| Reverse recovery charge | Q _{rr} | T _J = 25 °C | $V_{\rm R} = 200 \text{ V}$ | - | 2000 | 2400 | nC |
| Peak rate of recovery current | dI _{(rec)M} /dt | T _J = 25 °C | | - | - | 300 | A/µs |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|------------|-----------------------------------|---|-------------|-------|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Junction operating and storage temperature range | | T _J , T _{Stg} | | -40 to +150 | °C | |
| Maximum internal thermal r junction to case per leg | esistance, | R_{thJC} | DC operation | 0.18 | °C/W | |
| Typical thermal resistance, case to heatsink per modul | e | R _{thCS} | Mounting surface flat, smooth and greased | 0.05 | | |
| Mounting torque ± 10 % busb | | | A mounting compound is recommended and the torque should be rechecked after a period of 3 hours | 4 to 6 | Nm | |
| | | | to allow for the spread of the compound. | 4 10 0 | INIII | |
| Approximate weight | | | | 200 | g | |
| | | | | 7.1 | oz. | |
| Case style | | INT-A | -PAK | | | |

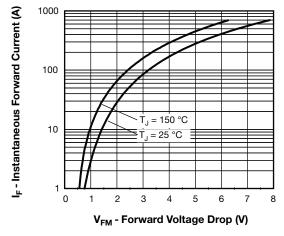


Fig. 1 - Maximum Forward Voltage Drop Characteristics

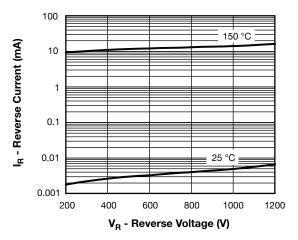


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

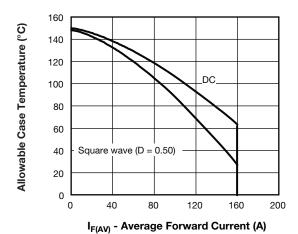


Fig. 3 - Maximum Allowable Case Temperature vs. Average Forward Current

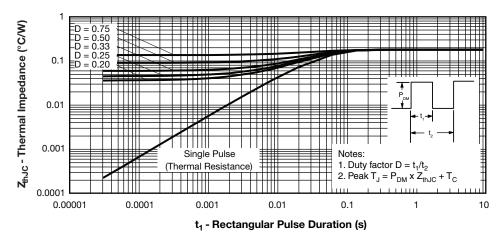


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

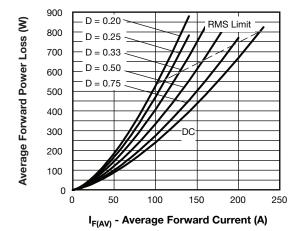


Fig. 5 - Forward Power Loss Characteristics

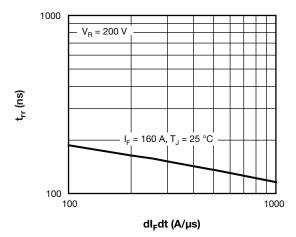


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt (Per Leg)

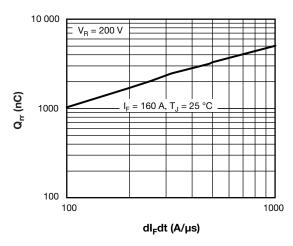


Fig. 7 - Typical Reverse Recovery Charge vs. dl_F/dt (Per Leg)

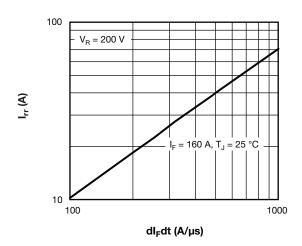
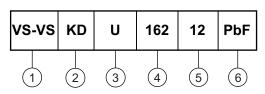


Fig. 8 - Typical Reverse Recovery Current vs. dl_F/dt (Per Leg)

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Circuit configuration

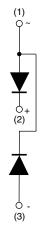
3 - U = HEXFRED® ultrafast diode

4 - Current rating

Voltage rating (12 = 1200 V)

6 - PbF = Lead (Pb)-free

CIRCUIT CONFIGURATION

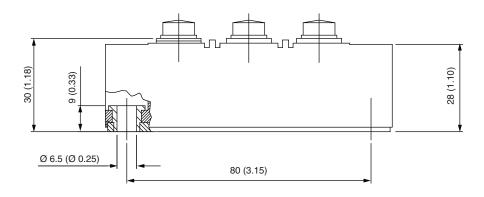


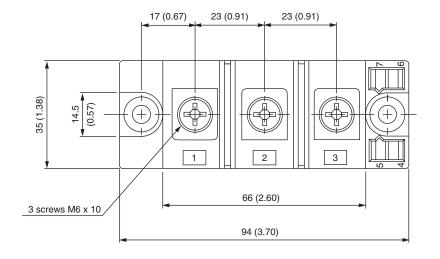
| LINKS TO RELATED DOCUMENTS | | | | |
|----------------------------|--------------------------|--|--|--|
| Dimensions | www.vishay.com/doc?95254 | | | |

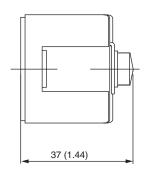


INT-A-PAK DBC

DIMENSIONS in millimeters (inches)









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Vishay

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